

TC4539BP/BF

C²MOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC

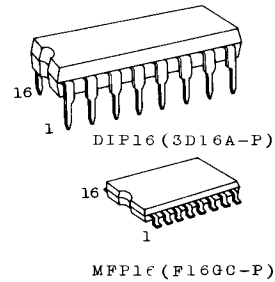
TC4539BP/TC4539BF DUAL 4-CHANNEL DATA SELECTOR/MULTIPLEXER

TC4539BP/BF contains two circuits of data selectors which select data according to common address inputs A and B.

Four channel data X0 through X3 are selected to be output Z according to inputs A and B and four channel data Y0 through Y3 are selected by the same A and B to generate output W.

When input St (ST') is set at "H", the output becomes "L" regardless other inputs.

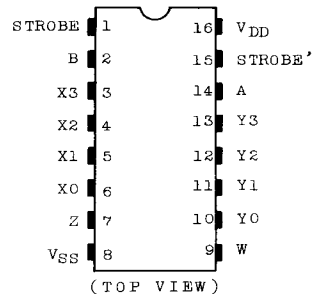
This can be widely applied in composition of signals, parallel to serial conversion and selection of signals.



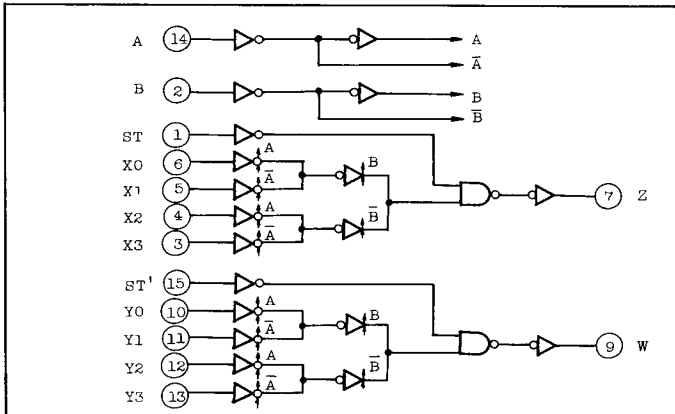
ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V _{DD}	V _{SS} - 0.5 ~ V _{SS} + 20	V
Input Voltage	V _{IN}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
Output Voltage	V _{OUT}	V _{SS} - 0.5 ~ V _{DD} + 0.5	V
DC Input Current	I _{IN}	±10	mA
Power Dissipation	PD	300 (DIP) / 180 (MFP)	mW
Operating Temperature Range	T _A	-40 ~ 85	°C
Storage Temperature Range	T _{stg}	-65 ~ 150	°C
Lead Temp./Time	T _{sol}	260°C • 10 sec	

PIN ASSIGNMENT



LOGIC DIAGRAM



TRUTH TABLE

A	B	ST' ST	X0 Y0	X1 Y1	X2 Y2	X3 Y3	Z W
*	*	H	*	*	*	*	L
L	L	L	L	*	*	*	L
L	L	L	H	*	*	*	H
H	L	L	*	L	*	*	L
H	L	L	*	H	*	*	H
L	H	L	*	*	L	*	L
L	H	L	*	*	H	*	H
H	H	L	*	*	*	L	L
H	H	L	*	*	*	H	H

* : DON'T CARE

RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	V _{DD}	3	-	18	V
Input Voltage	V _{IN}	0	-	V _{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V _{DD} (V)	-40°C		25°C			85°C		UNITS	
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Output Voltage	V _{OH}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	4.95	-	4.95	5.00	-	4.95	-	V	
			10	9.95	-	9.95	10.00	-	9.95	-		
			15	14.95	-	14.95	15.00	-	14.95	-		
Low-Level Output Voltage	V _{OL}	I _{OUT} < 1μA V _{IN} =V _{SS} , V _{DD}	5	-	0.05	-	0.00	0.05	-	0.05	V	
			10	-	0.05	-	0.00	0.05	-	0.05		
			15	-	0.05	-	0.00	0.05	-	0.05		
Output High Current	I _{OH}	V _{OH} =4.6V V _{OH} =2.5V V _{OH} =9.5V V _{OH} =13.5V V _{IN} =V _{SS} , V _{DD}	5	-0.61	-	-0.51	-1.0	-	-0.42	-	mA	
			5	-2.5	-	-2.1	-4.0	-	-1.7	-		
			10	-1.5	-	-1.3	-2.2	-	-1.1	-		
			15	-4.0	-	-3.4	-9.0	-	-2.8	-		
Output Low Current	I _{OL}	V _{OL} =0.4V V _{OL} =0.5V V _{OL} =1.5V V _{IN} =V _{SS} , V _{DD}	5	0.61	-	0.51	1.5	-	0.42	-	mA	
			10	1.5	-	1.3	3.8	-	1.1	-		
			15	4.0	-	3.4	15.0	-	2.8	-		
			15	4.0	-	3.4	15.0	-	2.8	-		
Input High Voltage	V _{IH}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	5	3.5	-	3.5	2.75	-	3.5	-	V	
			10	7.0	-	7.0	5.5	-	7.0	-		
			15	11.0	-	11.0	8.25	-	11.0	-		
			15	11.0	-	11.0	8.25	-	11.0	-		
Input Low Voltage	V _{IL}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V I _{OUT} < 1μA	5	-	1.5	-	2.25	1.5	-	1.5	V	
			10	-	3.0	-	5.5	3.0	-	3.0		
			15	-	4.0	-	8.25	4.0	-	4.0		
			15	-	4.0	-	8.25	4.0	-	4.0		
Input Current	"H" Level	I _{IH}	V _{IH} =18V	18	-	0.1	-	10 ⁻⁵	0.1	-	1.0	μA
	"L" Level	I _{IL}	V _{IL} =0V	18	-	-0.1	-	-10 ⁻⁵	-0.1	-	-1.0	
Quiescent Device Current	I _{DD}	V _{IN} =V _{SS} , V _{DD} *	5	-	5	-	0.001	5	-	150	μA	
			10	-	10	-	0.002	10	-	300		
			15	-	20	-	0.004	20	-	600		

* All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta=25°C, VSS=0V, CL=50pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	VDD(V)	MIN.	TYP.	MAX.	UNITS
Output Transition Time (Low to High)	t_{TLH}		5	-	80	200	ns
			10	-	50	100	
			15	-	40	80	
Output Transition Time (High to Low)	t_{THL}		5	-	80	200	
			10	-	50	100	
			15	-	40	80	
Propagation Delay Time (A - Z, W)	t_{pLH} t_{pHL}		5	-	150	450	
			10	-	60	220	
			15	-	40	170	
Propagation Delay Time (Xn, Yn - Z, W)	t_{pLH} t_{pHL}		5	-	130	420	
			10	-	60	180	
			15	-	40	140	
Propagation Delay Time (STROBE - Z, W)	t_{pLH} t_{pHL}		5	-	85	290	
			10	-	40	150	
			15	-	30	120	
Input Capacitance	CIN			-	5	7.5	pF

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

